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L. Spruell

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: SHINYA SATOU ET AL. *Lee OK*
Serial No.: 09/936,480 Group Art Unit: 2855
Filed: DECEMBER 26, 2001 Examiner: MARISSA L. FERGUSON
Title: SEMICONDUCTOR PRESSURE SENSOR AND PRESSURE
DETECTOR

REPLY UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

Sir:

The following amendments and remarks are respectfully submitted in
response to the Office Action dated October 2, 2002.

IN THE CLAIMS:

Please amend claims 1-9 as follows:

(A copy of the marked-up version of the amended claims are
attached to this Reply).

1. (Amended) A semiconductor pressure sensor, comprising:
- a substrate,
- a diaphragm formed on said substrate by a sacrificial layer etching
method, and